## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No	
Confirmation No9972	
Filing DateAugust 6, 2003	
nventor	
AssigneeMicron Technology, Inc.	
Group Art Unit	
Examiner Fuller, Eric B.	
Attorney's Docket NoMI22-2194	
Customer No	
Fitle: Methods of Forming Material on a Substrate, and Method of Forming a	
Field Effect Transistor Gate Oxide on a Substrate	

## **RESPONSE TO JUNE 20, 2006 OFFICE ACTION**

To: Mail Stop Amendment

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

From:

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## **AMENDMENTS**

In response to the Office Action of June 20, 2006, applicant amends and remarks as follows.